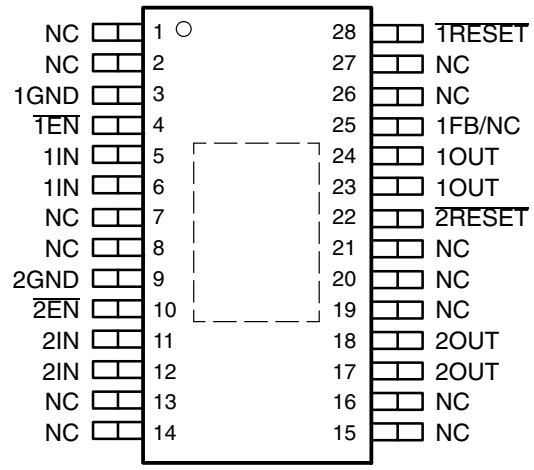
- **Qualified for Automotive Applications**
- **Dual Output Voltages for Split-Supply Applications**
- **Output Current Range of 0 mA to 1.0 A Per Regulator**
- **3.3-V/2.5-V, 3.3-V/1.8-V, and 3.3-V/Adjustable Output**
- **Fast-Transient Response**
- **2% Tolerance Over Load and Temperature**
- **Dropout Voltage Typically 350 mV at 1 A**
- **Ultra Low 85 μA Typical Quiescent Current**
- **1 μA Quiescent Current During Shutdown**
- **Dual Open Drain Power-On Reset With 200-ms Delay for Each Regulator**
- **28-Pin PowerPAD™ TSSOP Package**
- **Thermal Shutdown Protection for Each Regulator**

PWP PACKAGE
(TOP VIEW)



NC – No internal connection

description

The TPS767D3xx family of dual voltage regulators offers fast transient response, low dropout voltages and dual outputs in a compact package and incorporating stability with 10-μF low ESR output capacitors.

The TPS767D3xx family of dual voltage regulators is designed primarily for DSP applications. These devices can be used in any mixed-output voltage application, with each regulator supporting up to 1 A. Dual active-low reset signals allow resetting of core-logic and I/O separately.

AVAILABLE OPTIONS†‡

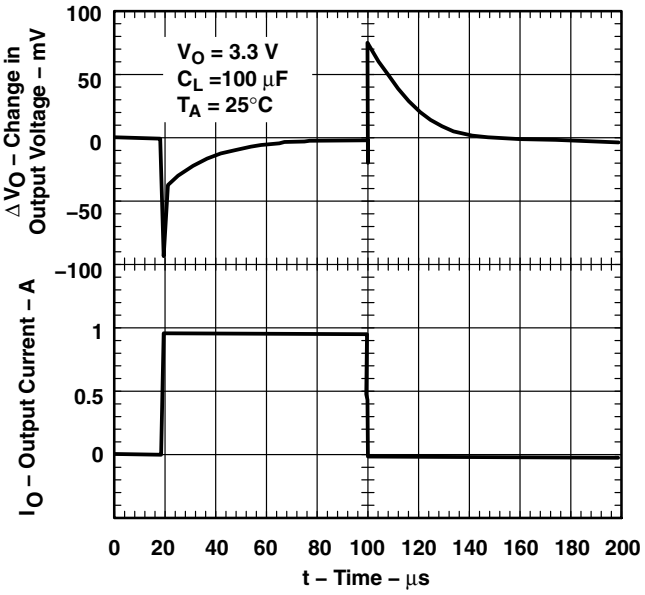
T_J	REGULATOR 1 V_O (V)	REGULATOR 2 V_O (V)	TSSOP (PWP)
–40°C to 125°C	Adj (1.5 – 5.5 V)	3.3 V	TPS767D301QPWPRQ1
	1.8 V	3.3 V	TPS767D318QPWPRQ1
	2.5 V	3.3 V	TPS767D325QPWPRQ1

† For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at http://www.ti.com.

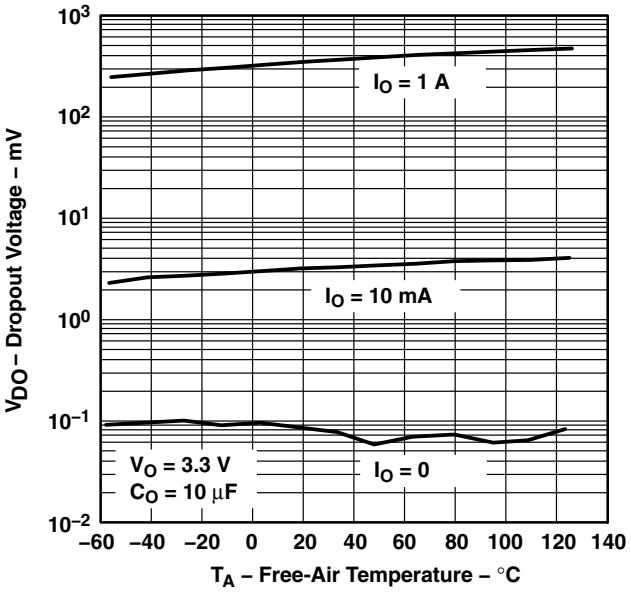
‡ Package drawings, thermal data, and symbolization are available at http://www.ti.com/packaging.

The TPS767D301 is adjustable using an external resistor divider (see application information). The PWP packages are taped and reeled as indicated by the R suffix on the device type (e.g., TPS767D301QPWPRQ1).

LOAD TRANSIENT RESPONSE



DROPOUT VOLTAGE vs FREE-AIR TEMPERATURE



description (continued)

Because the PMOS device behaves as a low-value resistor, the dropout voltage is very low (typically 350 mV at an output current of 1 A for the TPS767D325) and is directly proportional to the output current. Additionally, since the PMOS pass element is a voltage-driven device, the quiescent current is very low and independent of output loading (typically 85 μA over the full range of output current, 0 mA to 1 A). These two key specifications yield a significant improvement in operating life for battery-powered systems. This LDO family also features a sleep mode; applying a TTL high signal to $\overline{EN}$ (enable) shuts down the regulator, reducing the quiescent current to 1 μA at T_J = 25°C.

The $\overline{RESET}$ output of the TPS767D3xx initiates a reset in microcomputer and microprocessor systems in the event of an undervoltage condition. An internal comparator in the TPS767D3xx monitors the output voltage of the regulator to detect an undervoltage condition on the regulated output voltage.

The TPS767D3xx is offered in 1.8-V, 2.5-V, and 3.3-V fixed-voltage versions and in an adjustable version (programmable over the range of 1.5 V to 5.5 V). Output voltage tolerance is specified as a maximum of 2% over line, load, and temperature ranges. The TPS767D3xx family is available in 28 pin PWP TSSOP package. They operate over a junction temperature range of –40°C to 125°C.

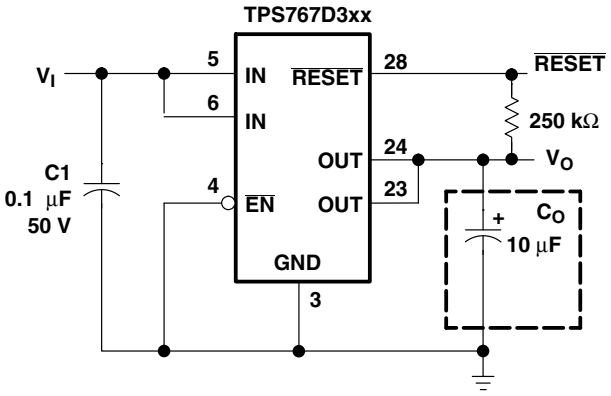
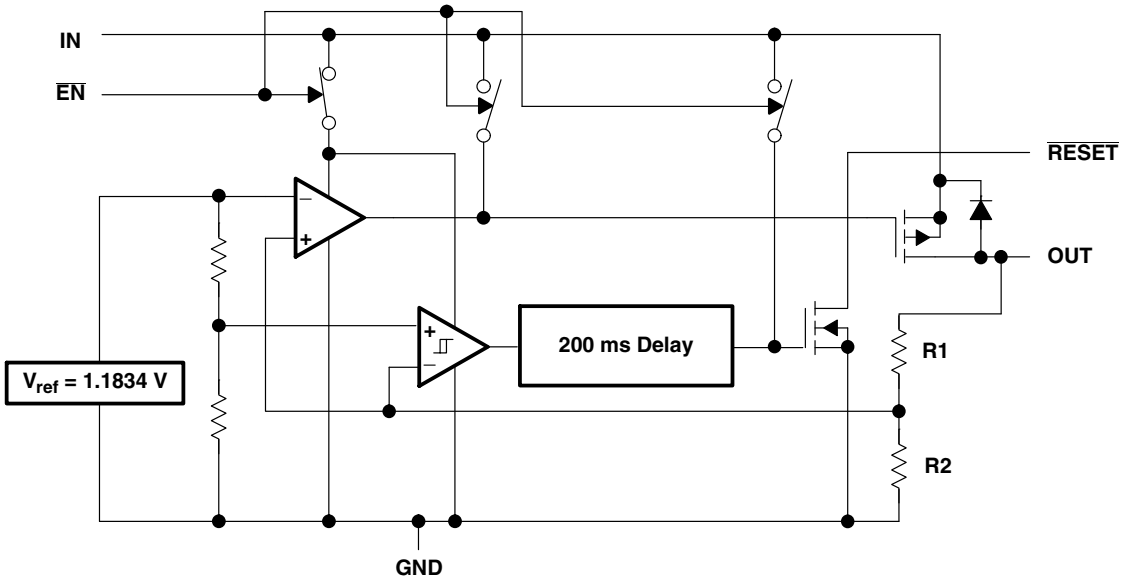
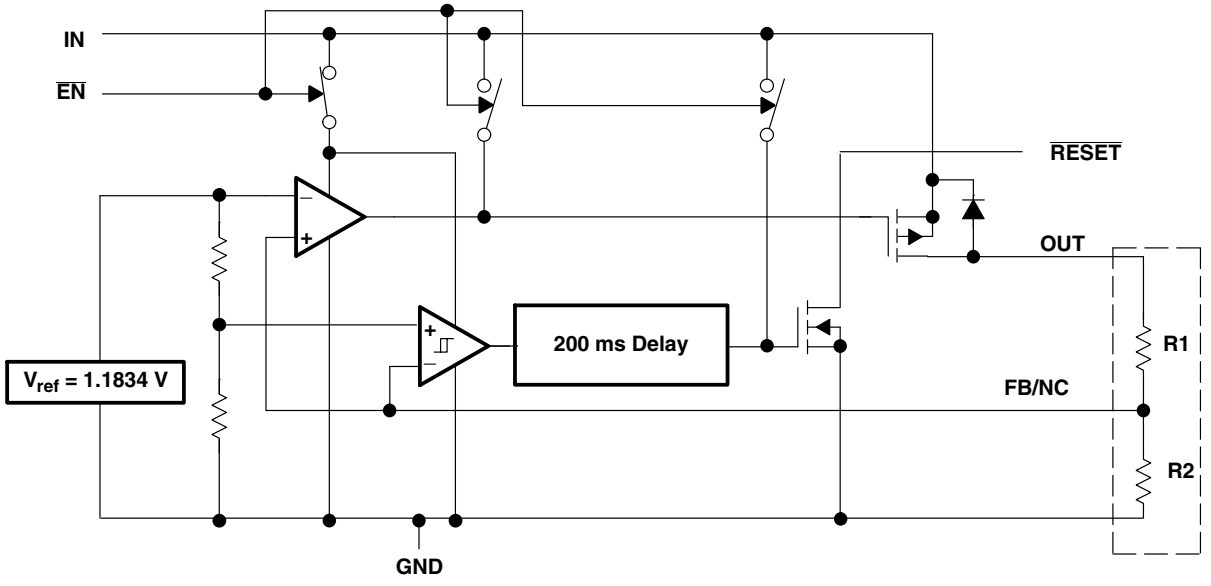


Figure 1. Typical Application Circuit (Fixed Versions) for Single Channel

functional block diagram—adjustable version (for each LDO)



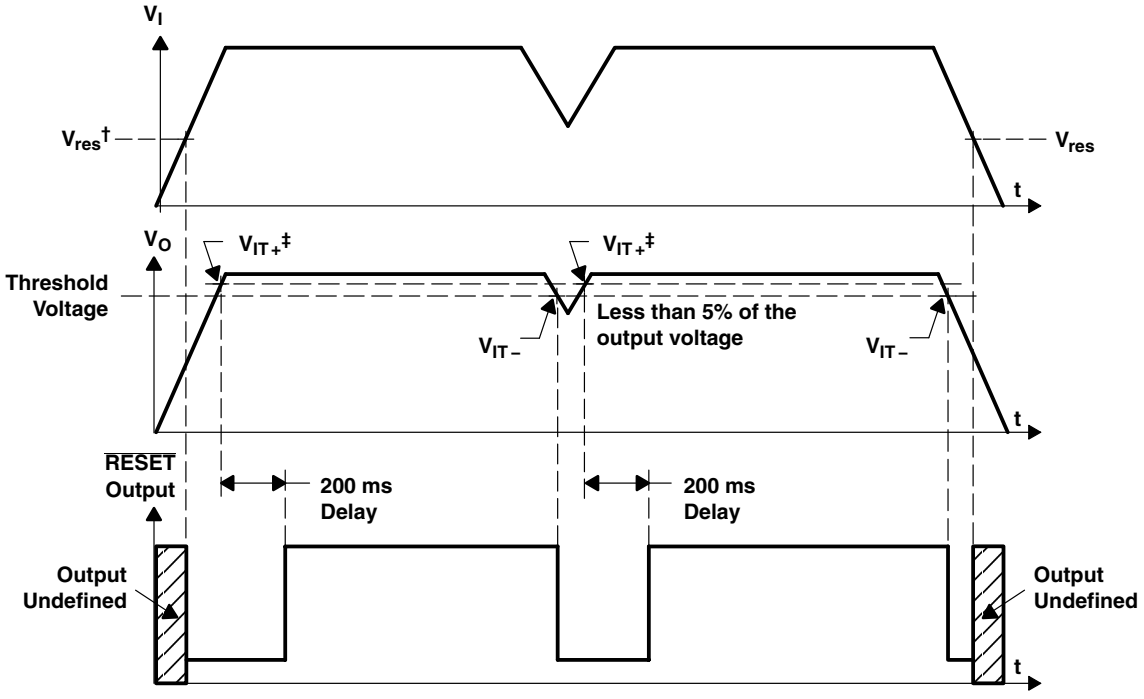
functional block diagram—fixed-voltage version (for each LDO)



Terminal Functions

TERMINAL NAME	TERMINAL NO.	I/O	DESCRIPTION
1GND	3		Regulator #1 ground
$\overline{1EN}$	4	I	Regulator #1 enable
1IN	5, 6	I	Regulator #1 input supply voltage
2GND	9		Regulator #2 ground
$\overline{2EN}$	10	I	Regulator #2 enable
2IN	11, 12	I	Regulator #2 input supply voltage
2OUT	17, 18	O	Regulator #2 output voltage
$\overline{2RESET}$	22	O	Regulator #2 reset signal
1OUT	23, 24	O	Regulator #1 output voltage
1FB/NC	25	I	Regulator #1 output voltage feedback for adjustable and no connect for fixed output
$\overline{1RESET}$	28	O	Regulator #1 reset signal
NC	1, 2, 7, 8, 13–16, 19, 20, 21, 26, 27		No connection

timing diagram



† V_{res} is the minimum input voltage for a valid $\overline{RESET}$. The symbol V_{res} is not currently listed within EIA or JEDEC standards for semiconductor symbology.

‡ VIT –Trip voltage is typically 5% lower than the output voltage (95%V_O)

absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Input voltage range‡, V_I . . . . . –0.3 V to 13.5 V
Input voltage range, V_I (1IN, 2IN, $\overline{EN}$) . . . . . –0.3 V to V_I + 0.3 V
Output voltage, V_O (1OUT, 2OUT) . . . . . 7 V
Output voltage, V_O ($\overline{RESET}$) . . . . . 16.5 V
Peak output current . . . . . Internally limited
ESD rating, HBM . . . . . 2 kV
Continuous total power dissipation . . . . . See dissipation rating tables
Operating virtual junction temperature range, T_J . . . . . –40°C to 150°C
Storage temperature range, T_{stg} . . . . . –65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
‡ All voltage values are with respect to network terminal ground.

DISSIPATION RATING TABLE

PACKAGE	AIR FLOW (CFM)	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 70°C$ POWER RATING	$T_A = 85°C$ POWER RATING
PWP§	0	3.58 W	35.8 mW/°C	1.97 W	1.43 W
	250	5.07 W	50.7 mW/°C	2.79 W	2.03 W

This parameter is measured with the recommended copper heat sink pattern on a 4–layer PCB, 1 oz. copper on 4–in x 4–in ground layer. For more information, refer to TI technical brief literature number SLMA002.

recommended operating conditions

	MIN	MAX	UNIT
Input voltage, V_I¶ (1IN, 2IN)	2.7	10	V
Output current for each LDO, I_O (Note 1)	0	1.0	A
Output voltage range, V_O (1OUT, 2OUT)	1.5	5.5	V
Operating virtual junction temperature, T_J	–40	125	°C

¶ To calculate the minimum input voltage for your maximum output current, use the following equation: $V_{I(min)} = V_{O(max)} + V_{DO(max\ load)}$.
NOTE 1: Continuous current and operating junction temperature are limited by internal protection circuitry, but it is not recommended that the device operate under conditions beyond those specified in this table for extended periods of time.

electrical characteristics, $V_i = V_{O(nom)} + 1$ V, $I_O = 1$ mA, $\overline{EN} = 0$, $C_O = 10\ \mu F$ (unless otherwise noted)

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
Output voltage (V_O) (see Note 2)		Adjustable	1.5 V ≤ V_O ≤ 5.5 V, 10 μA < I_O < 1 A	T_J = 25°C		V_O		V
				T_J = –40°C to 125°C	0.98V_O		1.02V_O	
		1.8 V Ouput	2.8 V < V_I < 10 V, 10 μA < I_O < 1 A	T_J = 25°C		1.8		
				T_J = –40°C to 125°C	1.764		1.836	
		2.5 V Output	3.5 V < V_I < 10 V, 10 μA < I_O < 1 A	T_J = 25°C		2.5		
				T_J = –40°C to 125°C	2.45		2.55	
		3.3 V Output	4.3 V < V_I < 10 V, 10 μA < I_O < 1 A	T_J = 25°C		3.3		V
				T_J = –40°C to 125°C	3.234		3.366	
Quiescent current (GND current) for each LDO (see Note 2)			10 μA < I_O < 1 A,	T_J = 25°C		85		μA
			I_O = 1 A,	T_J = –40°C to 125°C			125	
Output voltage line regulation for each LDO ($\Delta V_O/V_O$) (see Notes 2 and 3)			V_O + 1 V < V_I ≤ 10 V,	T_J = 25°C		0.01		%/V
Output noise voltage			BW = 200 Hz to 100 kHz, V_O = 1.8 V, I_C = 1 A, C_O = 10 μF,	T_J = 25°C		55		μVrms
Output current limit for each LDO			V_O = 0 V			1.7	2	A
Thermal shutdown juction temperature						150		°C
Standby current for each LDO			2.7 < V_I < 10V, T_J = 25°C,	$\overline{EN}$ = V_I,		1		μA
			2.7 < V_I < 10V, T_J = –40°C to 125°C	$\overline{EN}$ = V_I,			10	μA
FB input current		Adjustable	FB = 1.5 V			2		nA
High level enable input voltage					2.0			V
Low level enable input voltage							0.8	V
Power supply ripple rejection (see Note 2)			f = 1 KHz, T_J = 25°C,	C_O = 10 μF		60		dB
Reset	Minimum input voltage for valid $\overline{RESET}$		$I_{O(RESET)}$ = 300 μA			1.1		V
	Trip threshold voltage		V_O decreasing		92		98	%V_O
	Hysteresis voltage		Measured at V_O			0.5		%V_O
	Output low voltage		V_I = 2.7 V,	$I_{O(RESET)}$ = 1 mA		0.15	0.4	V
	Leakage current		$V_{(RESET)}$ = 7 V				1	μA
	RESET time-out delay					200		mA

NOTES: 2. Minimum IN operating voltage is 2.7 V or $V_{O(typ)}$ + 1 V, whichever is greater. maximum IN voltage 10V.

3. If VO ≤ 1.8 V, V_{Imin} = 2.7 V, and V_{Imax} = 10 V:

$$\text{Line Reg. (mV)} = (\%/V) \times \frac{V_O\left(V_{Imax} - 2.7\ V\right)}{100} \times 1000$$

If VO ≥ 2.5 V, V_{Imin} = Vo + 1 V, and V_{Imax} = 10 V:

$$\text{Line Reg. (mV)} = (\%/V) \times \frac{V_O\left(V_{Imax} - \left(V_O + 1\ V\right)\right)}{100} \times 1000$$

electrical characteristics, $V_i = V_{O(nom)} + 1$ V, $I_O = 1$ mA, $\overline{EN} = 0$, $C_O = 10\ \mu F$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Input current ($\overline{EN}$)	$\overline{EN} = 0$ V		–1	0	1	μA
	$\overline{EN} = V_I$		–1		1	
Load regulation				3		mV
Dropout voltage (see Note 4)	$V_O = 3.3$ V, $I_O = 1$ A	$T_J = 25°C$		350		mV
		$T_J = –40°C$ to $125°C$			575	

NOTE 4: IN voltage equals Vo(Typ) – 100mV; Adjustable output voltage set to 3.3V nominal with external resistor divider. 1.8V, and 2.5V dropout voltage is limited by input voltage range limitations.

TYPICAL CHARACTERISTICS

Table of Graphs

		FIGURE
Output voltage	vs Output current	2, 3, 4
	vs Free-air temperature	5, 6, 7
Ground current	vs Free-air temperature	8, 9
Power supply ripple rejection	vs Frequency	10
Output spectral noise density	vs Frequency	11
Output impedance	vs Frequency	12
Dropout voltage	vs Free-air temperature	13
Line transient response		14, 16
Load transient response		15, 17
Output voltage	vs Time	18
Dropout voltage	vs Input voltage	19
Equivalent series resistance (ESR)	vs Output current, $T_A = 25°C$	21
	vs Output current, $T_J = 125°C$	22
	vs Output Current, $T_A = 25°C$	23
	vs Output current, $T_J = 125°C$	24

TYPICAL CHARACTERISTICS

OUTPUT VOLTAGE vs OUTPUT CURRENT

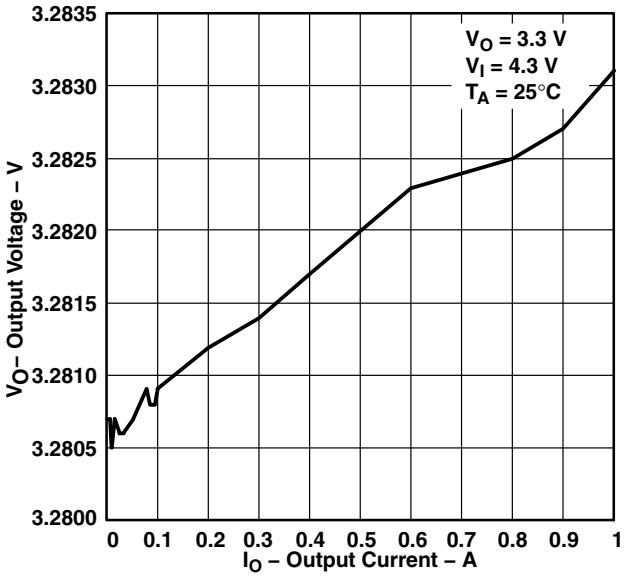


Figure 2

OUTPUT VOLTAGE vs OUTPUT CURRENT

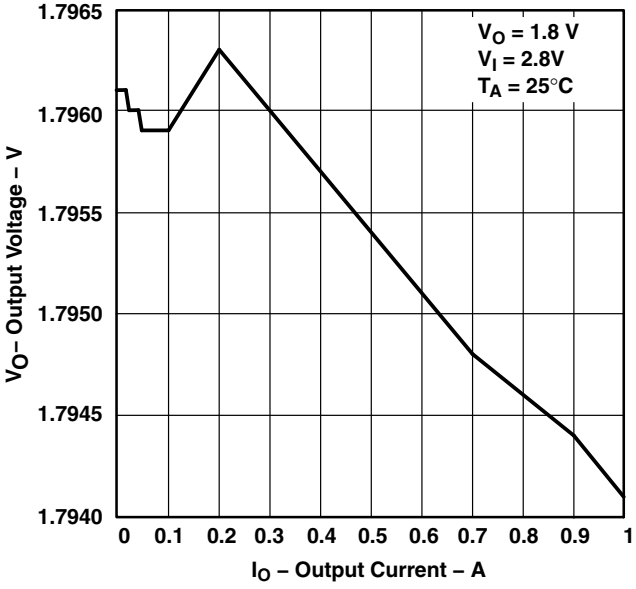


Figure 3

OUTPUT VOLTAGE vs OUTPUT CURRENT

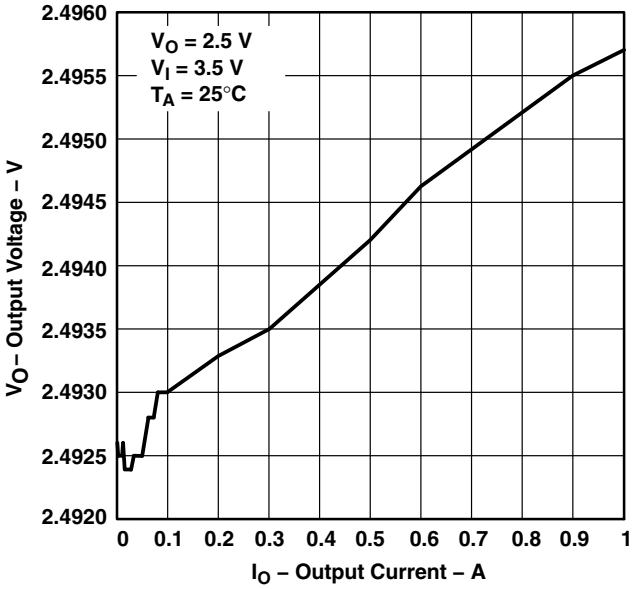


Figure 4

OUTPUT VOLTAGE vs FREE-AIR TEMPERATURE

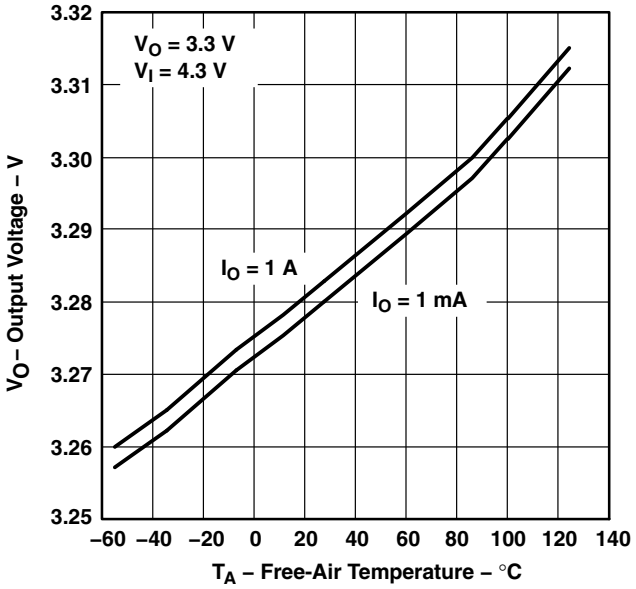


Figure 5

TYPICAL CHARACTERISTICS

OUTPUT VOLTAGE vs FREE-AIR TEMPERATURE

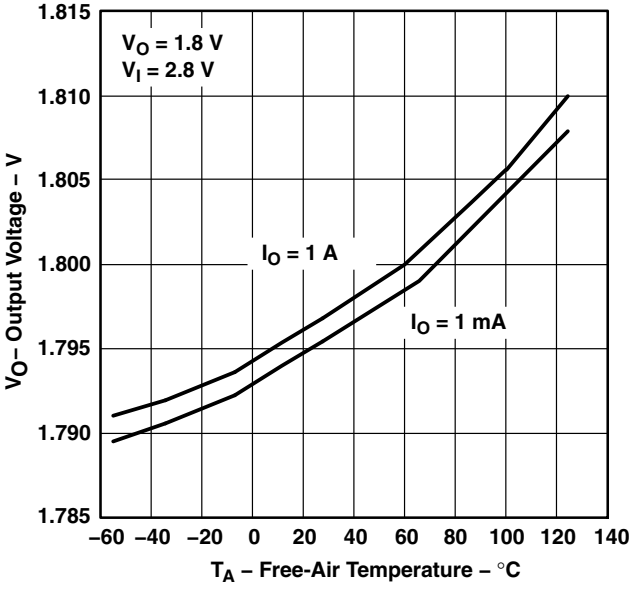


Figure 6

OUTPUT VOLTAGE vs FREE-AIR TEMPERATURE

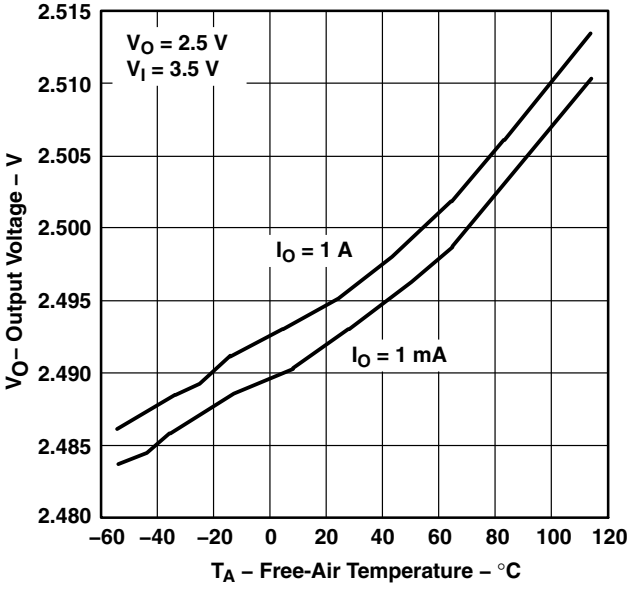


Figure 7

GROUND CURRENT vs FREE-AIR TEMPERATURE

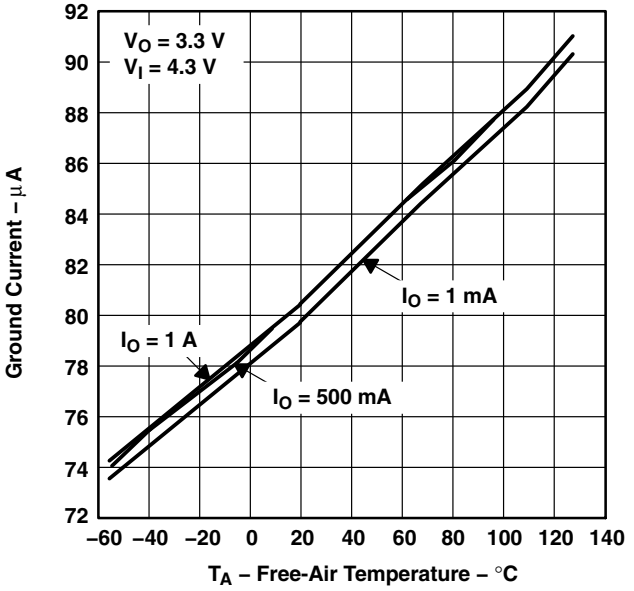


Figure 8

GROUND CURRENT vs FREE-AIR TEMPERATURE

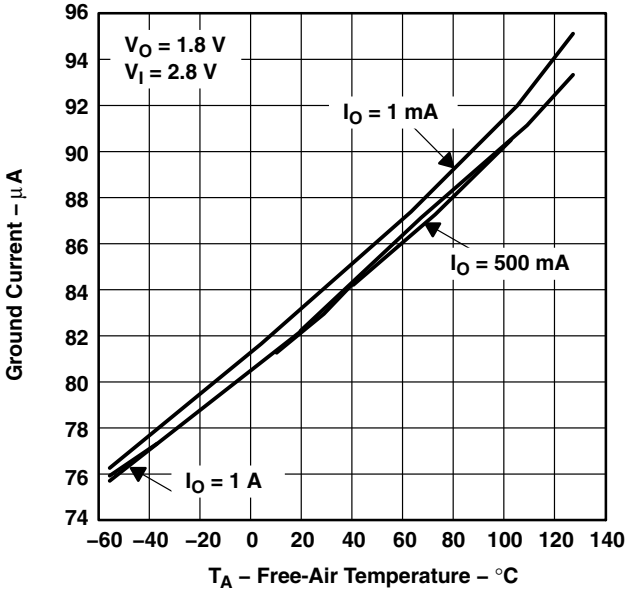


Figure 9

TYPICAL CHARACTERISTICS

POWER SUPPLY RIPPLE REJECTION vs FREQUENCY

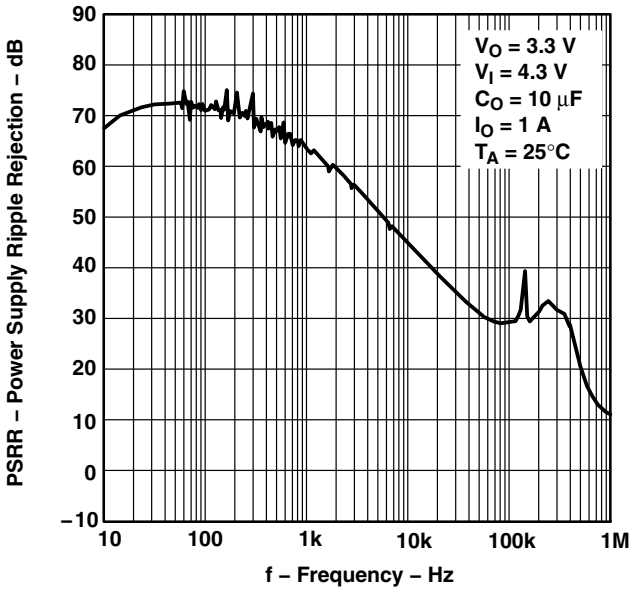


Figure 10

OUTPUT SPECTRAL NOISE DENSITY vs FREQUENCY

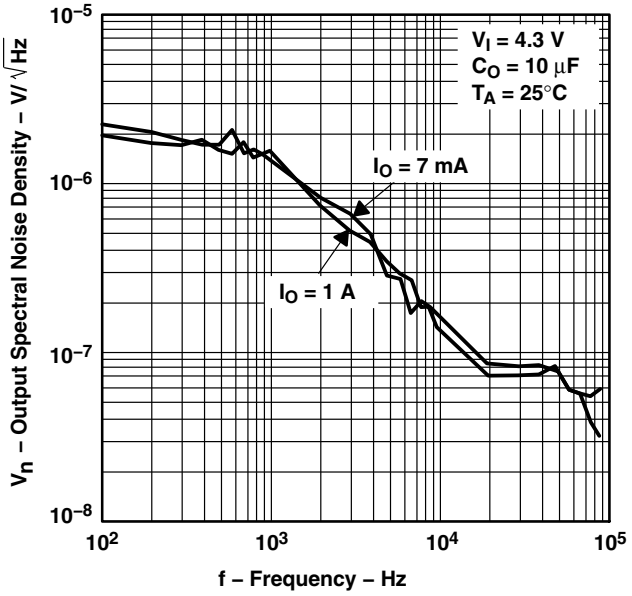


Figure 11

OUTPUT IMPEDANCE vs FREQUENCY

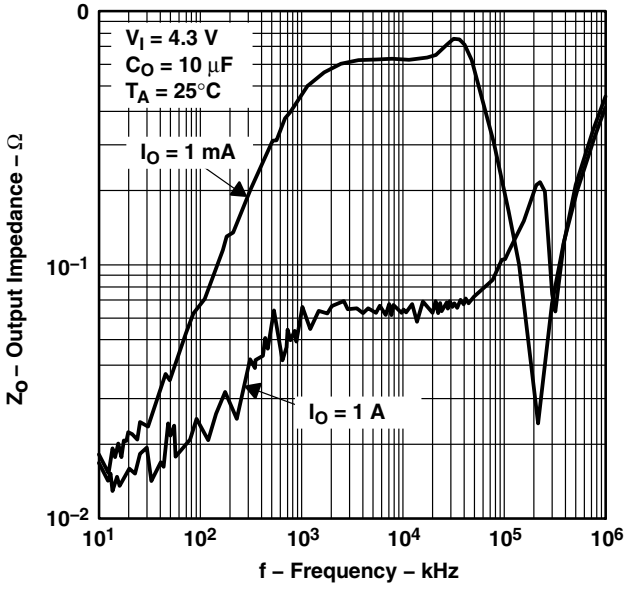


Figure 12

DROPOUT VOLTAGE vs FREE-AIR TEMPERATURE

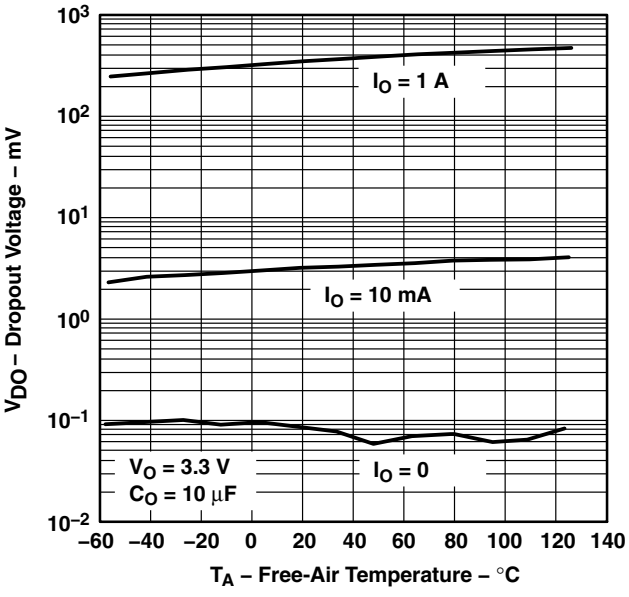


Figure 13

TYPICAL CHARACTERISTICS

LINE TRANSIENT RESPONSE

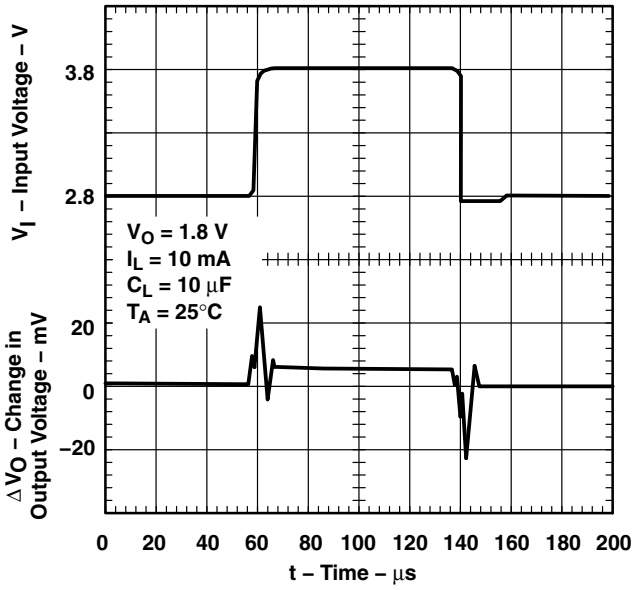


Figure 14

LOAD TRANSIENT RESPONSE

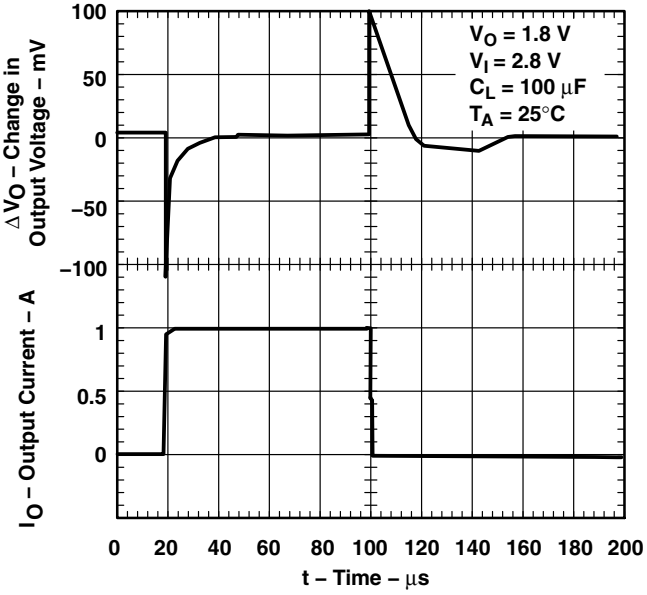


Figure 15

LINE TRANSIENT RESPONSE

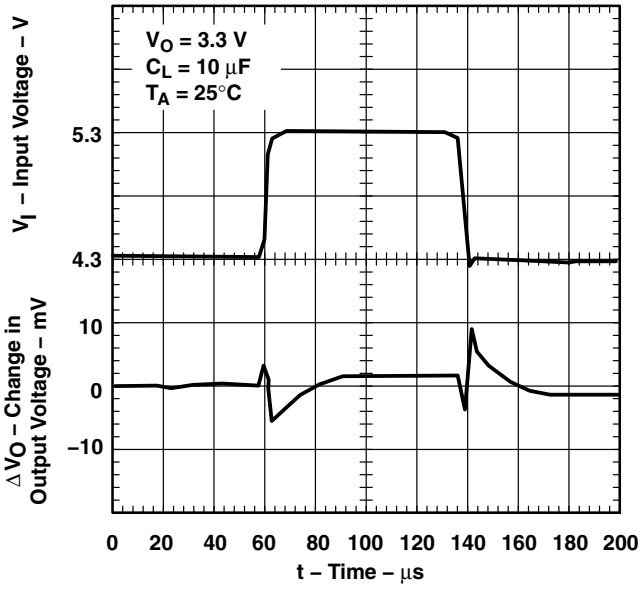


Figure 16

LOAD TRANSIENT RESPONSE

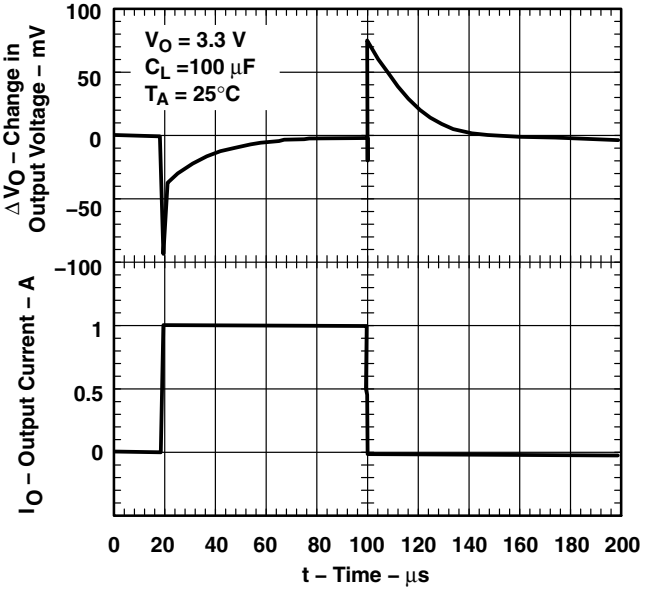


Figure 17

TYPICAL CHARACTERISTICS

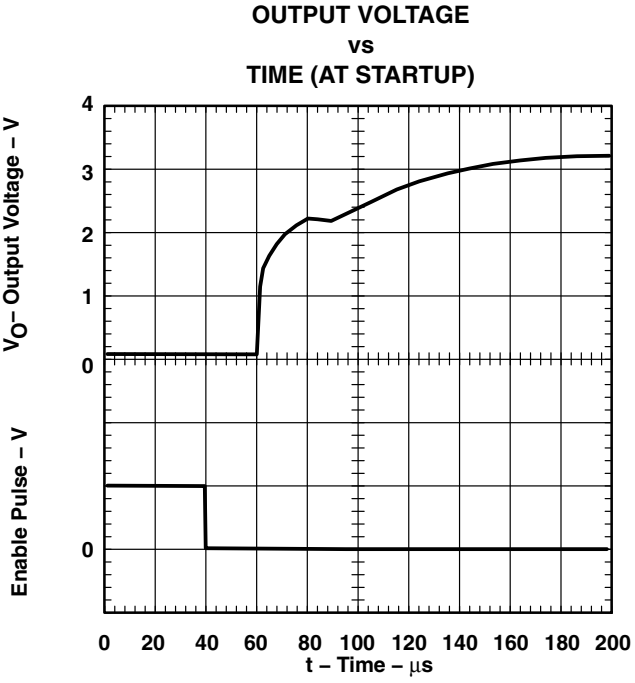


Figure 18

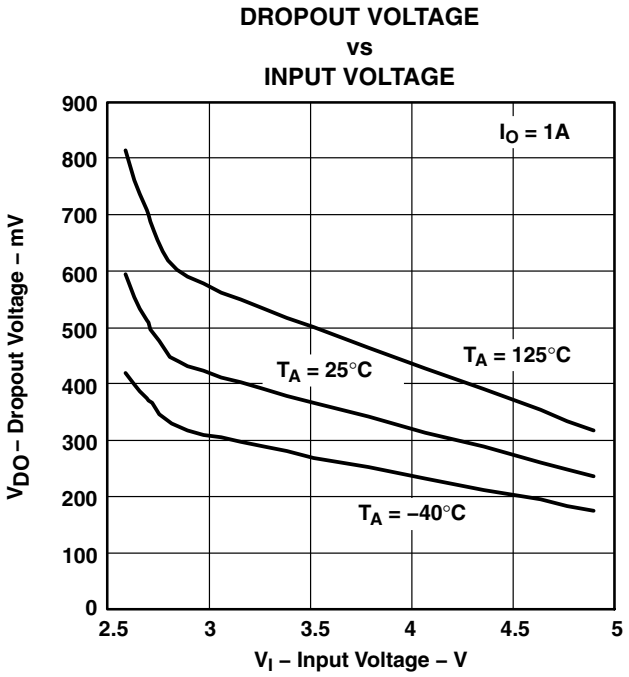


Figure 19

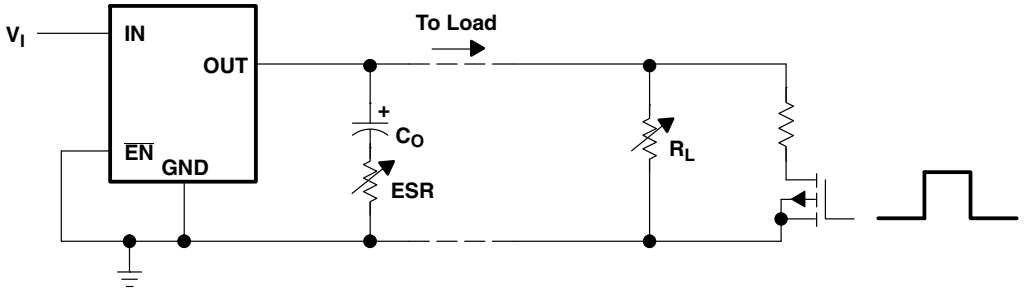


Figure 20. Test Circuit for Typical Regions of Stability (Figures 21 through 24) (fixed output options)

TYPICAL CHARACTERISTICS

TYPICAL REGION OF STABILITY
EQUIVALENT SERIES RESISTANCE†
vs
OUTPUT CURRENT

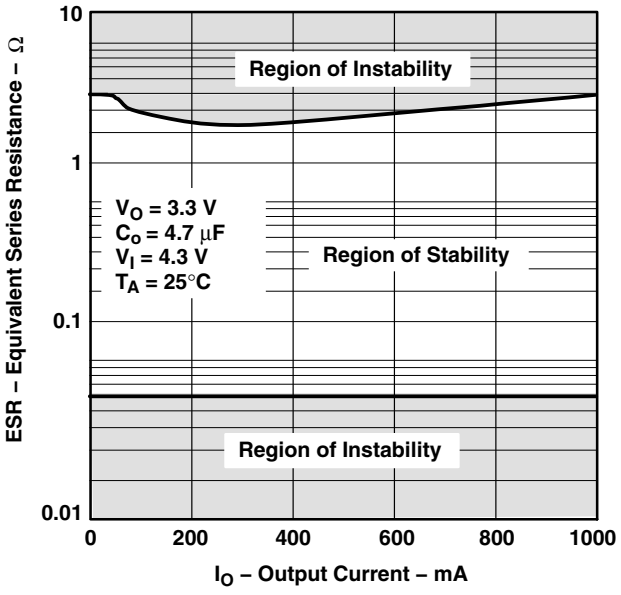


Figure 21

TYPICAL REGION OF STABILITY
EQUIVALENT SERIES RESISTANCE†
vs
OUTPUT CURRENT

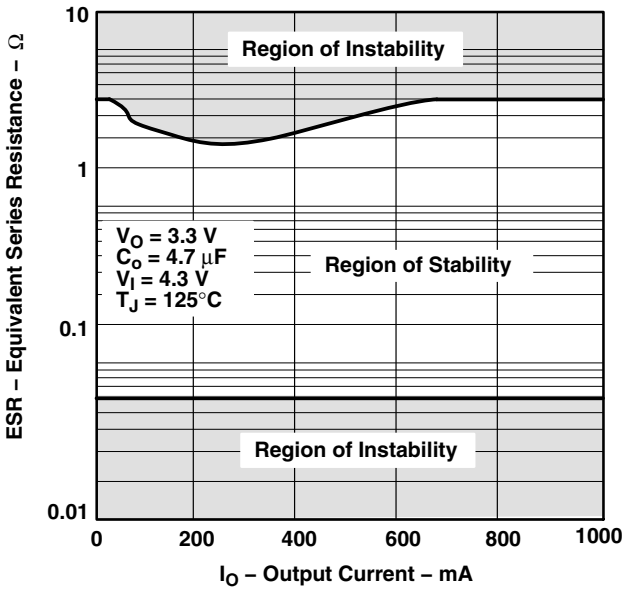


Figure 22

TYPICAL REGION OF STABILITY
EQUIVALENT SERIES RESISTANCE†
vs
OUTPUT CURRENT

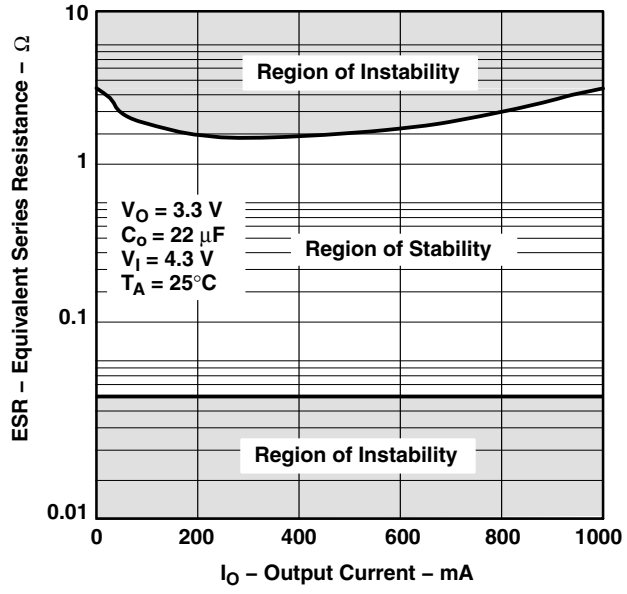


Figure 23

TYPICAL REGION OF STABILITY
EQUIVALENT SERIES RESISTANCE†
vs
OUTPUT CURRENT

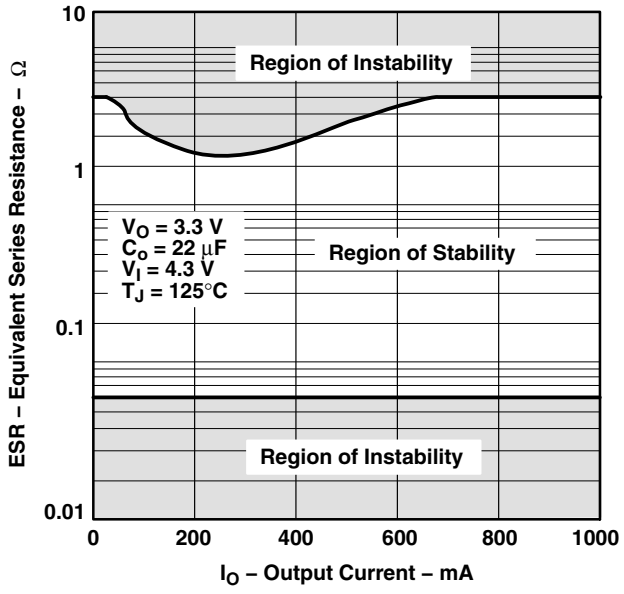


Figure 24

† Equivalent series resistance (ESR) refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_O.

APPLICATION INFORMATION

The features of the TPS767D3xx family (low-dropout voltage, ultra low quiescent current, power-saving shutdown mode, and a supply-voltage supervisor) and the power-dissipation properties of the TSSOP PowerPAD package have enabled the integration of the dual LDO regulator with high output current for use in DSP and other multiple voltage applications. Figure 25 shows a typical dual-voltage DSP application.

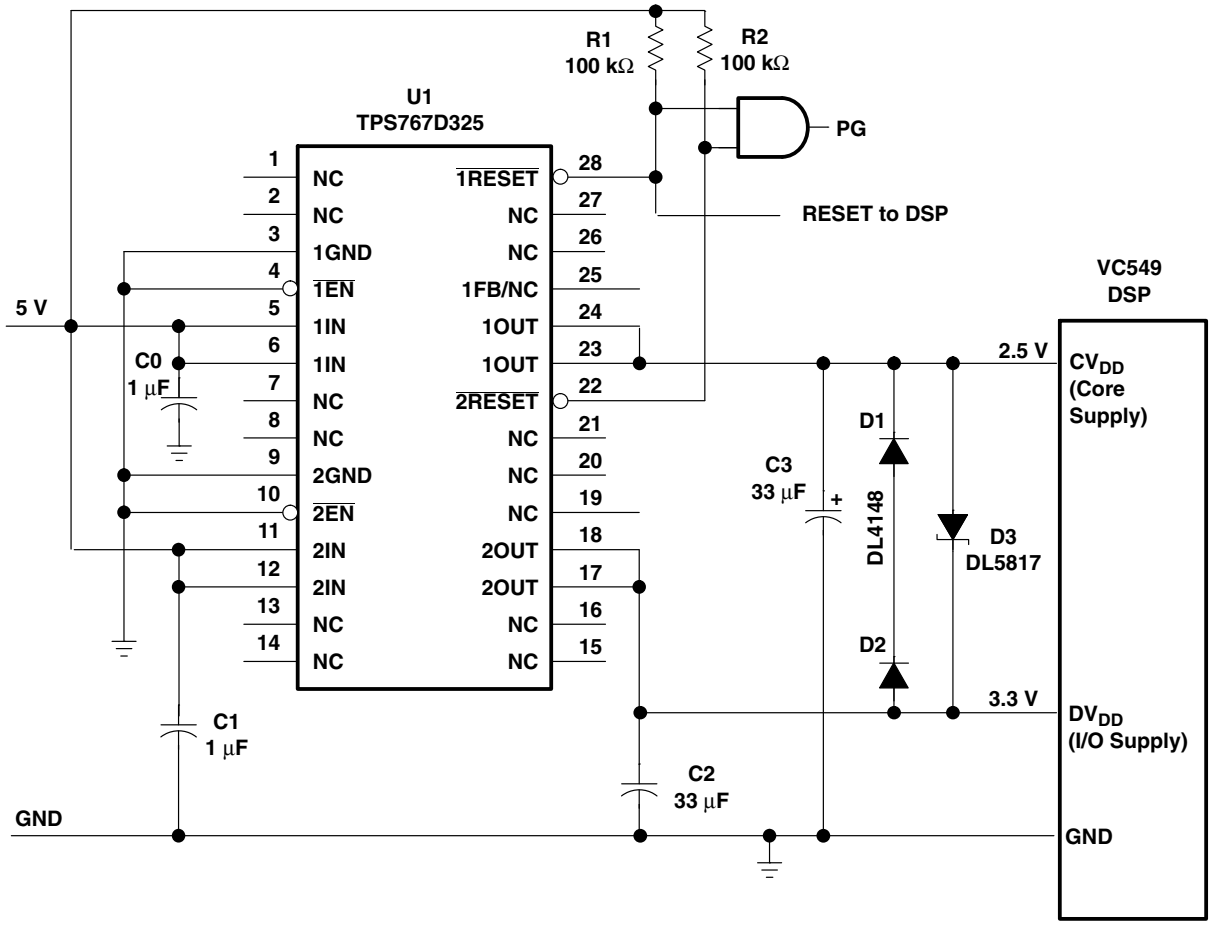


Figure 25. Dual-Voltage DSP Application

DSP power requirements include very high transient currents that must be considered in the initial design. This design uses higher-valued output capacitors to handle the large transient currents.

device operation

The TPS767D3xx features very low quiescent current, which remain virtually constant even with varying loads. Conventional LDO regulators use a pnp pass element, the base current of which is directly proportional to the load current through the regulator ($I_B = I_C/\beta$). Close examination of the data sheets reveals that these devices are typically specified under near no-load conditions; actual operating currents are much higher as evidenced by typical quiescent current versus load current curves. The TPS767D3xx uses a PMOS transistor to pass current; because the gate of the PMOS is voltage driven, operating current is low and invariable over the full load range. The TPS767D3xx specifications reflect actual performance under load condition.

device operation (continued)

Another pitfall associated with the pnp-pass element is its tendency to saturate when the device goes into dropout. The resulting drop in β forces an increase in I_B to maintain the load. During power up, this translates to large start-up currents. Systems with limited supply current may fail to start up. In battery-powered systems, it means rapid battery discharge when the voltage decays below the minimum required for regulation. The TPS767D3xx quiescent current remains low even when the regulator drops out, eliminating both problems.

The TPS767D3xx family also features a shutdown mode that places the output in the high-impedance state (essentially equal to the feedback-divider resistance) and reduces quiescent current to under 2 μA. If the shutdown feature is not used, $\overline{EN}$ should be tied to ground. Response to an enable transition is quick; regulated output voltage is typically reestablished in 120 μs.

minimum load requirements

The TPS767D3xx family is stable even at zero load; no minimum load is required for operation.

FB - pin connection (adjustable version only)

The FB pin is an input pin to sense the output voltage and close the loop for the adjustable option. The output voltage is sensed through a resistor divider network as is shown in Figure 27 to close the loop. Normally, this connection should be as short as possible; however, the connection can be made near a critical circuit to improve performance at that point. Internally, FB connects to a high-impedance wide-bandwidth amplifier and noise pickup feeds through to the regulator output. Routing the FB connection to minimize/avoid noise pickup is essential. In fixed output options this pin is a no connect.

external capacitor requirements

An input capacitor is not required; however, a ceramic bypass capacitor (0.047 pF to 0.1 μF) improves load transient response and noise rejection when the TPS767D3xx is located more than a few inches from the power supply. A higher-capacitance electrolytic capacitor may be necessary if large (hundreds of milliamps) load transients with fast rise times are anticipated.

Like all low dropout regulators, the TPS767D3xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance value is 10 μF and the ESR (equivalent series resistance) must be between 60 mΩ and 1.5 Ω. Capacitor values 10 μF or larger are acceptable, provided the ESR is less than 1.5 Ω. Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described previously.

external capacitor requirements (continued)

When necessary to achieve low height requirements along with high output current and/or high ceramic load capacitance, several higher ESR capacitors can be used in parallel to meet the previous guidelines.

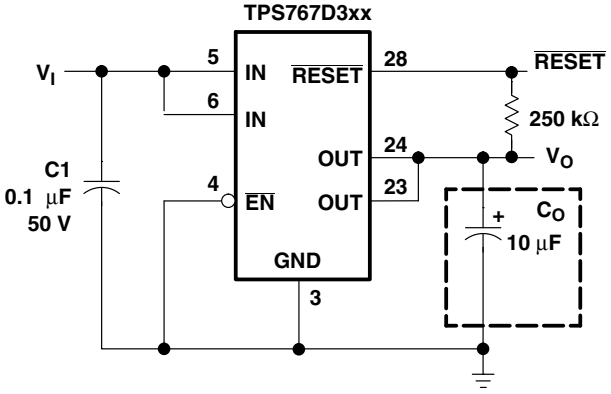


Figure 26. Typical Application Circuit (Fixed Versions) for Single Channel

programming the TPS767D301 adjustable LDO regulator

The output voltage of the TPS767D301 adjustable regulator is programmed using an external resistor divider as shown in Figure 27. The output voltage is calculated using:

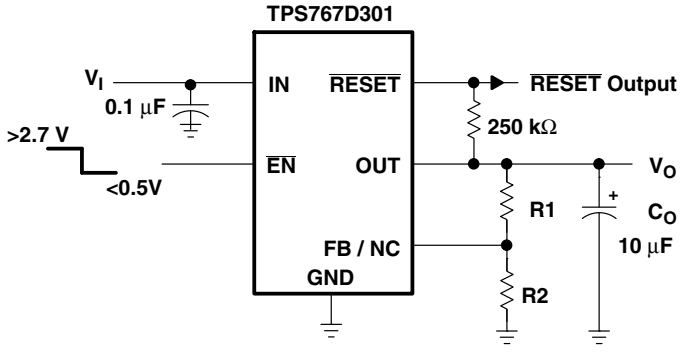
$$V_O = V_{ref} \times \left(1 + \frac{R1}{R2}\right) \quad (1)$$

where:

V_{ref} = 1.1834 V typ (the internal reference voltage)

Resistors R1 and R2 should be chosen for approximately 50-μA divider current. Lower value resistors can be used but offer no inherent advantage and waste more power. Higher values should be avoided as leakage currents at FB increase the output voltage error. The recommended design procedure is to choose R2 = 30.1 kΩ to set the divider current at 50 μA and then calculate R1 using:

$$R1 = \left(\frac{V_O}{V_{ref}} - 1\right) \times R2 \quad (2)$$



OUTPUT VOLTAGE PROGRAMMING GUIDE

OUTPUT VOLTAGE	R1	R2	UNIT
2.5 V	33.2	30.1	kΩ
3.3 V	53.6	30.1	kΩ
3.6 V	61.9	30.1	kΩ
4 75V	90.8	30.1	kΩ

Figure 27. TPS767D301 Adjustable LDO Regulator Programming

Reset indicator

The TPS767D3xx features a $\overline{\text{RESET}}$ output that can be used to monitor the status of the regulator. The internal comparator monitors the output voltage: when the output drops to 95% (typical) of its regulated value, the $\overline{\text{RESET}}$ output transistor turns on, taking the signal low. The open-drain output requires a pullup resistor. If not used, it can be left floating. $\overline{\text{RESET}}$ can be used to drive power-on reset circuitry or as a low-battery indicator.

regulator protection

The TPS767D3xx PMOS-pass transistor has a built-in back-gate diode that safely conducts reverse currents when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. When extended reverse voltage is anticipated, external limiting may be appropriate.

The TPS767D3xx also features internal current limiting and thermal protection. During normal operation, the TPS767D3xx limits output current to approximately 1.7 A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 150°C(typ), thermal-protection circuitry shuts it down. Once the device has cooled below 130°C(typ), regulator operation resumes.

power dissipation and junction temperature

Specified regulator operation is assured to a junction temperature of 125°C; the maximum junction temperature should be restricted to 125°C under normal operating conditions. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$, and the actual dissipation, P_D, which must be less than or equal to $P_{D(max)}$.

The maximum-power-dissipation limit is determined using the following equation:

$$P_{D(max)} = \frac{T_J max - T_A}{R_{\theta JA}}$$

where:

$T_J max$ is the maximum allowable junction temperature

$R_{\theta JA}$ is the thermal resistance junction-to-ambient for the package, i.e., 27.9°C/W for the 28-terminal PWP with no airflow.

T_A is the ambient temperature.

The regulator dissipation is calculated using:

$$P_D = \left(V_I - V_O\right) \times I_O$$

Power dissipation resulting from quiescent current is negligible. Excessive power dissipation will trigger the thermal protection circuit.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS767D301QPWPRQ1	Active	Production	HTSSOP (PWP) | 28	2000 | LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	767D301Q1
TPS767D318QPWPRQ1	Active	Production	HTSSOP (PWP) | 28	2000 | LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	767D318Q1

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

OTHER QUALIFIED VERSIONS OF TPS767D3-Q1 :

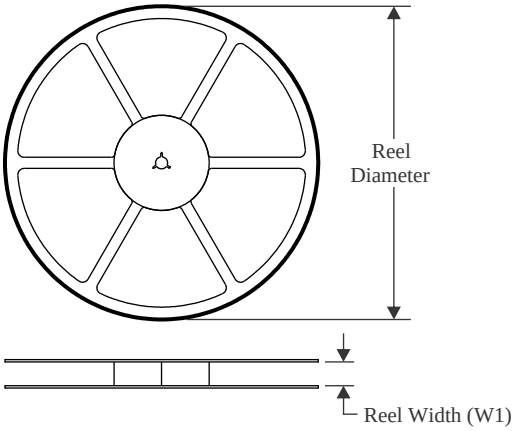
- Catalog : TPS767D3

NOTE: Qualified Version Definitions:

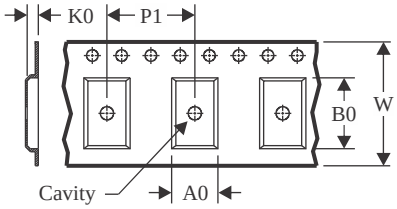
- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

REEL DIMENSIONS

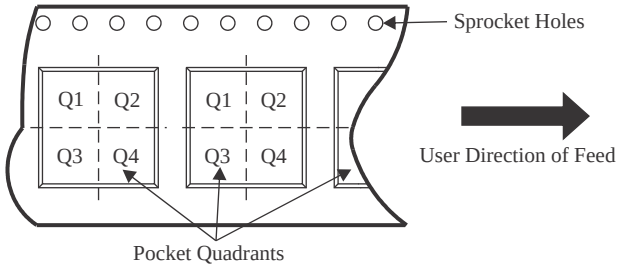


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

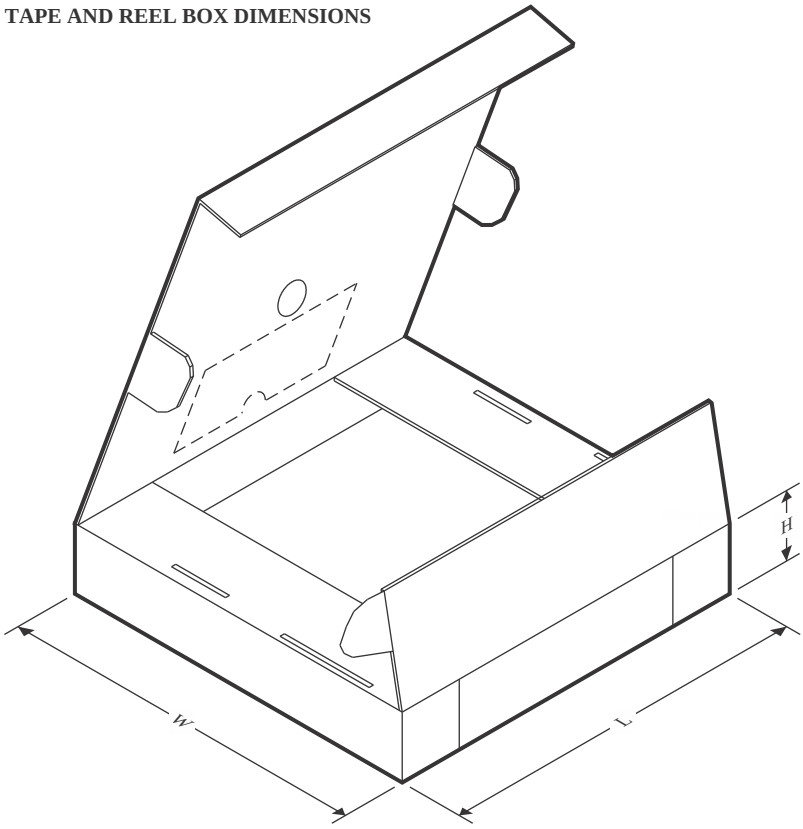
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS767D301QPWPRQ1	HTSSOP	PWP	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
TPS767D318QPWPRQ1	HTSSOP	PWP	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS767D301QPWPRQ1	HTSSOP	PWP	28	2000	350.0	350.0	43.0
TPS767D318QPWPRQ1	HTSSOP	PWP	28	2000	350.0	350.0	43.0

GENERIC PACKAGE VIEW

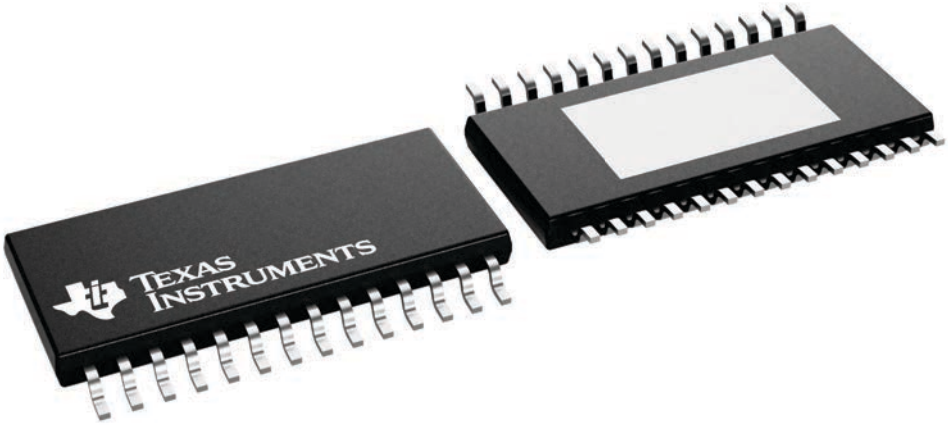
PWP 28

PowerPAD™ TSSOP - 1.2 mm max height

4.4 x 9.7, 0.65 mm pitch

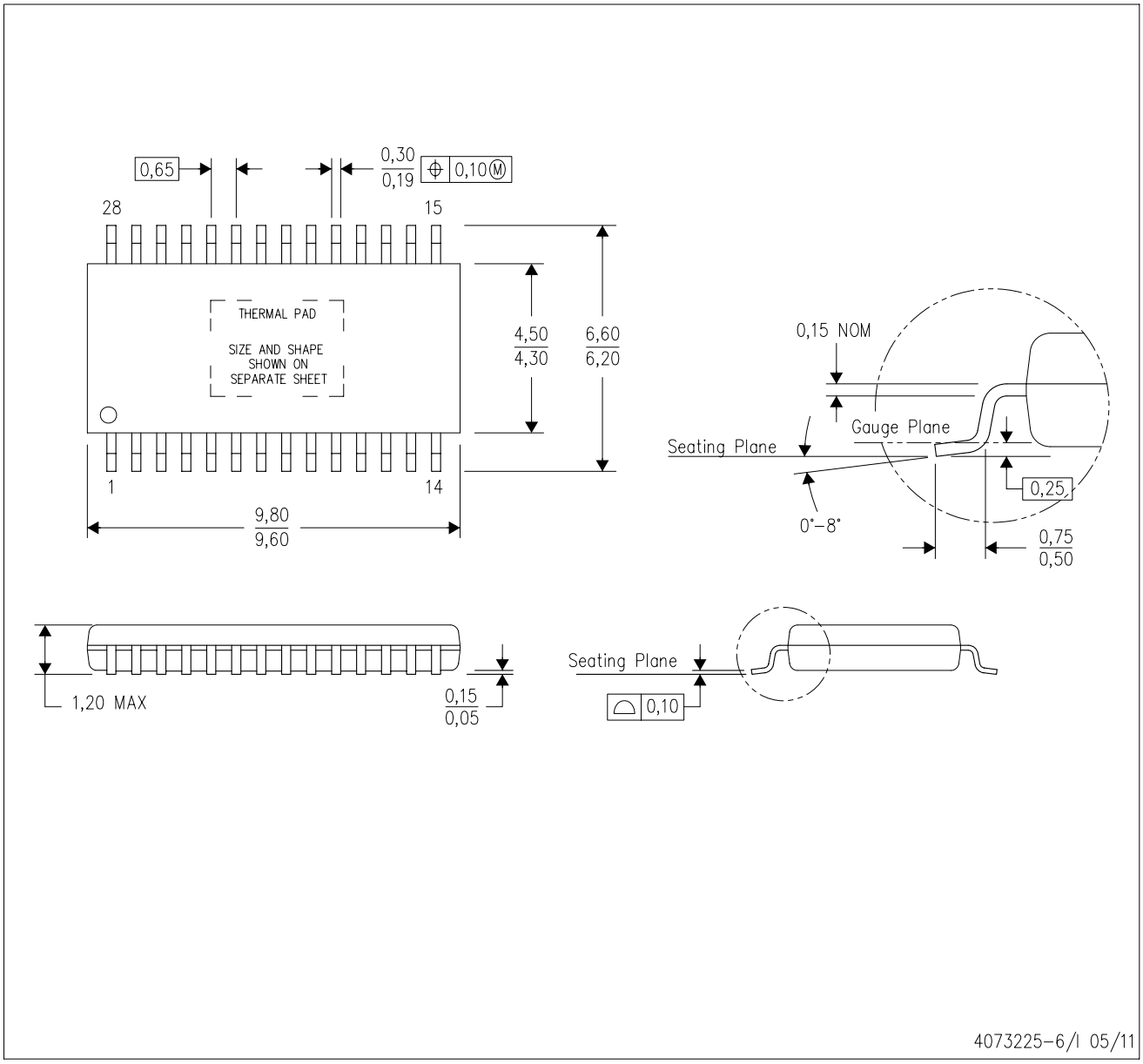
SMALL OUTLINE PACKAGE

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4224765/B

PWP (R–PDSO–G28) PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <http://www.ti.com>.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
E. Falls within JEDEC MO–153

PowerPAD is a trademark of Texas Instruments.

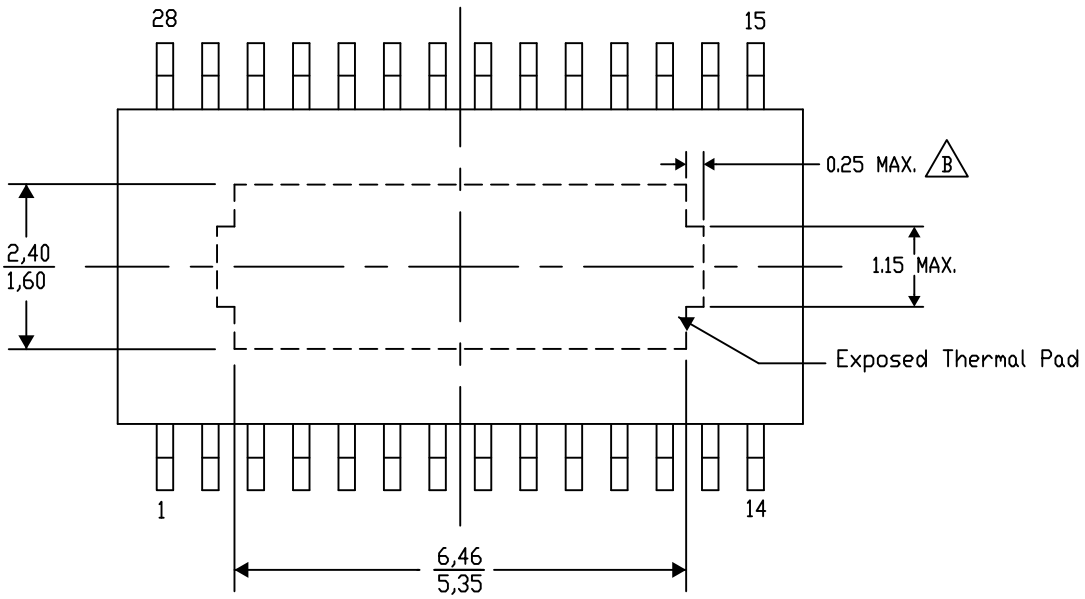
PWP (R–PDSO–G28) PowerPAD™ SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

Exposed Thermal Pad Dimensions

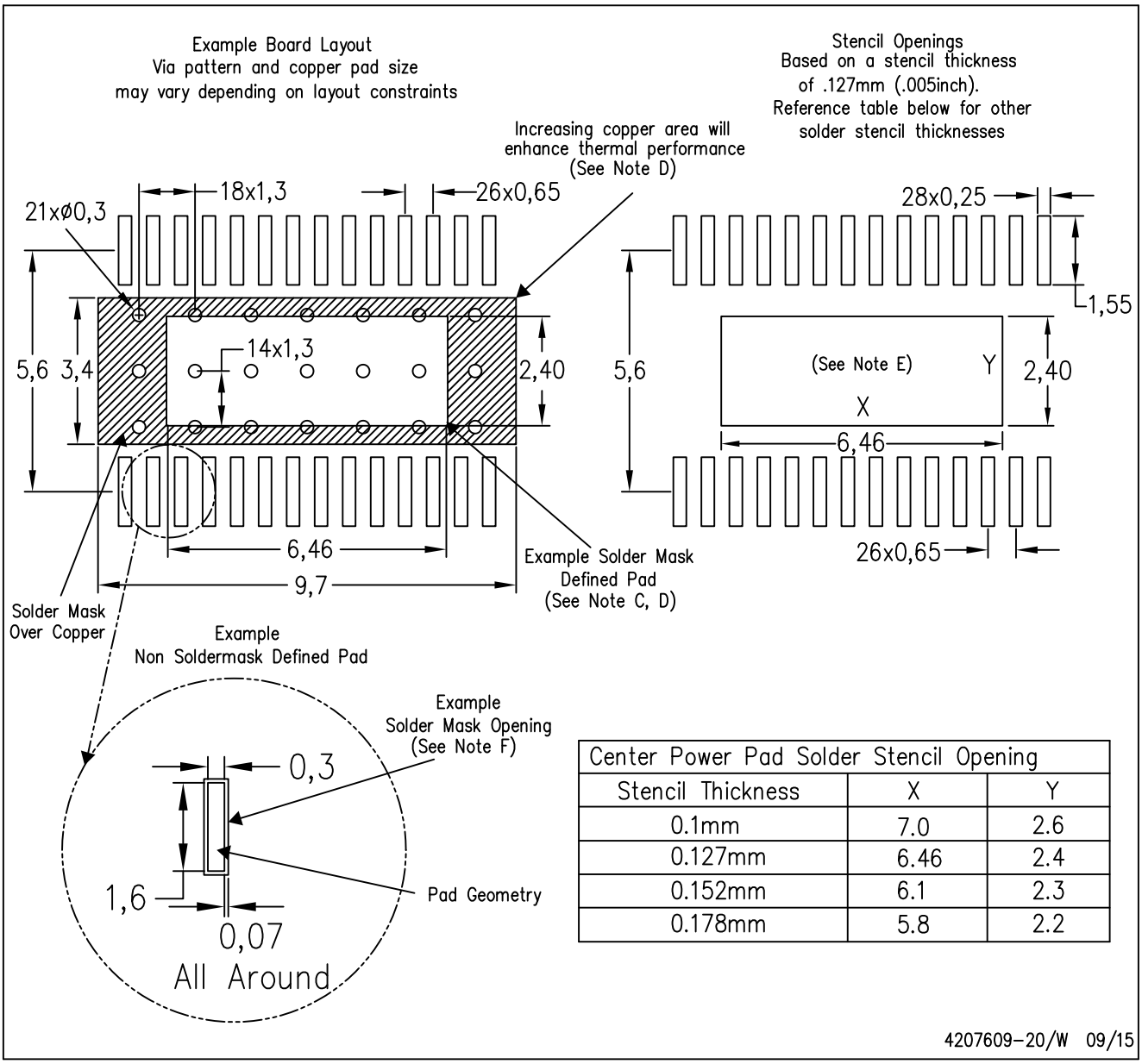
4206332–34/AO 01/16

NOTE: A. All linear dimensions are in millimeters

B. Exposed tie strap features may not be present.

PowerPAD is a trademark of Texas Instruments

PWP (R–PDSO–G28) PowerPAD™ PLASTIC SMALL OUTLINE



Center Power Pad Solder Stencil Opening		
Stencil Thickness	X	Y
0.1mm	7.0	2.6
0.127mm	6.46	2.4
0.152mm	6.1	2.3
0.178mm	5.8	2.2

4207609–20/W 09/15

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>. Publication IPC–7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC–7525 for other stencil recommendations.
F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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